

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	"5710449".ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 16:58
L2	1	"5710449".pn. and undoped	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 17:25
L3	1	"20020146897".pn. and photoresist	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 17:25
S1	2	"6730619".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 12:23
S2	2	"6569782".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 21:46
S3	0	woo-chan-jung.inv.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 21:46
S4	0	woo-chan-jeon.inv.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 21:47
S5	15	jung-woo-chan.inv.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 21:47

S6	2	jung-woo-chan.inv. and flowing and oxidizing	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 21:49
S7	2	jung-woo-chan.inv. and ratio and oxidizing	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 21:49
S8	79	blanket adj insulating adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 13:19
S9	972	(etch adj stop adj layer) with (insulating adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 13:19
S10	251	(etch adj stop adj layer) near (insulating adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 13:41
S11	43	(etch adj stop adj layer) near (insulation adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 13:43
S12	22	(etch adj stop adj layer) near (insulative adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 14:13
S13	27	(etch adj stop adj layer) near (insulator adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 15:17

S14	9	(etch adj stop adj layer) near (insulating adj film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 14:29
S15	10	(etch adj stop adj layer) near (insulation adj film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 14:30
S16	0	(etch adj stop adj layer) near (insulative adj film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 14:30
S17	0	(etch adj stop adj layer) near (insulator adj film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 14:30
S18	10	(etch adj stop adj layer) near (dielectric adj film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 14:31
S19	388	(etch adj stop adj layer) near (dielectric adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 15:02
S20	669	257/324.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 15:03
S21	156	257/325.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 15:03

S22	241	257/326.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 15:04
S23	222	257/333.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 15:06
S24	202	257/389.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 16:30
S25	134	257/395.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 15:12
S27	736	257/632.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 15:12
S28	105	257/636.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 16:56
S29	257	257/641.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 16:56
S30	447	257/644.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 16:56

S31	185	257/650.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 08:56
S32	2	"6569782".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 08:58
S33	2	"6730619".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 08:58
S34	0	(etch adj stop adj layer) near (undoped adj insulator adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 15:17
S35	0	(etch adj stop adj layer) near (undoped adj insulating adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 15:17
S36	0	(etch adj stop adj layer) near (undoped adj insulation adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 15:18
S37	0	(etch adj stop adj layer) near (undoped adj insulative adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 15:18
S38	2	(etch adj stop adj layer) with (undoped adj insulating adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 15:19

S39	5	(etch adj stop adj layer) same (undoped adj insulating adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 16:17
S40	8	(etch adj stop adj layer) and (undoped adj insulating adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 16:17
S41	0	(etch adj stop adj layer) same (undoped adj insulation adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 16:18
S42	5	(etch adj stop adj (layer or film)) same (undoped adj insulating)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 16:20
S43	0	(etch adj stop adj (layer or film)) same (undoped adj insulation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 16:21
S44	0	(etch adj stop adj (layer or film)) same (undoped adj insulative)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 16:21
S45	0	(etch adj stop adj (layer or film)) same (undoped adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 16:31
S46	0	(etch adj stop adj (layer or film)) and (undoped adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 17:02

S47	0	(etch adj stop) near (undoped adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 17:02
S48	0	(etch adj stop) with (undoped adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 17:03
S49	0	(etch adj stop) same (undoped adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 17:03
S50	6	(etch adj stop) and (undoped adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 17:06
S51	12	(etch adj stop) and (undoped adj insulating)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 17:06
S52	1	(etch adj stop) and (undoped adj insulation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 17:08
S53	0	(etch adj stop) and (undoped adj insulative)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 17:08
S54	28	(etch adj stop) and (undoped adj dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:12

S55	67	(etch adj stop) and (undoped adj silicon adj nitride)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:13
S56	2	(etch adj stop) and (undoped adj sin)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:14
S57	0	(etch adj stop) and (undoped adj s3in4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:14
S58	0	(etch adj stop) and (undoped adj "s. sub.3in.sub.4")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:14
S59	1	(etch adj stop) and (undoped adj sio)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:15
S60	129	(etch adj stop) and (undoped adj silicon adj oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:21
S61	203	(etch adj stop) and (undoped adj silicon adj dioxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:42
S62	1	(etch adj stop) and (undoped adj sio2)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:44



S63	78	(etch adj stop) and (undoped adj "sio. sub.2")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/03 18:44
S64	2	"4845054".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:30
S65	2	"5104482".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:31
S66	2	"6054397".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:31
S67	2	"5336640".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:32
S68	2	"6013583".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:32
S69	2	"4879253".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:32
S70	2	"5180692".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:32

S71	2	"5409742".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:32
S72	2	"6057250".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:33
S73	2	"5286681".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:33
S74	2	"4668973".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:33
S75	2	"6261975".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:33
S76	2	"5862057".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:34
S77	2	"5888910".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:34
S78	2	"6159870".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:34

S79	2	"5646075".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:34
S80	2	"6114216".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:34
S81	2	"6090725".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/09 13:35
S83	37	(undoped adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:49
S84	9	(undoped adj insulation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 12:34
S85	103	(undoped adj insulating)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 16:58
S86	7	(undoped adj insulative)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 13:44
S87	2	(undoped adj insulated)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 13:44

S88	12	(undoped adj insulating) and (etch adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:28
S89	6	(undoped adj insulator) and (etch adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:51
S90	0	(undoped adj insulator) near (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:53
S91	0	(undoped adj insulated) near (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:53
S92	0	(undoped adj insulation) near (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:53
S93	0	(undoped adj insulating) near (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:53
S94	0	(undoped adj insulating) with (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:54
S95	0	(undoped adj insulative) with (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:54

S96	0	(undoped adj insulator) with (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:54
S97	1	(undoped adj insulator) and (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:54
S98	0	(undoped adj insulation) and (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 14:54
S99	0	(undoped adj insulating) and (cmp adj stop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:03
S10 0	6	(undoped adj insulating) with (sin or (silicon adj nitride)) with insulating	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:04
S10 1	3	(undoped adj insulator) with (sin or (silicon adj nitride)) with insulator	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:05
S10 2	0	(undoped adj insulated) with (sin or (silicon adj nitride)) with insulated	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:05
S10 3	0	(undoped adj insulative) with (sin or (silicon adj nitride)) with insulative	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:06

S10 4	1	(undoped adj insulation) with (sin or (silicon adj nitride)) with insulation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:06
S10 5	1	(undoped adj insulation) same (sin or (silicon adj nitride)) same insulation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:07
S10 6	0	(undoped adj insulative) same (sin or (silicon adj nitride)) same insulative	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:07
S10 7	8	(undoped adj insulating) same (sin or (silicon adj nitride)) same insulating	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:09
S10 8	0	(undoped adj insulated) same (sin or (silicon adj nitride)) same insulated	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:09
S10 9	7	(undoped adj insulator) same (sin or (silicon adj nitride)) same insulator	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:10
S11 0	19	(undoped adj insulator) and (sin or (silicon adj nitride)) and insulator	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:11
S11 1	0	(undoped adj insulated) and (sin or (silicon adj nitride)) and insulated	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:11

S11 2	6	(undoped adj insulative) and (sin or (silicon adj nitride)) and insulative	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:13
S11 3	3	(undoped adj insulation) and (sin or (silicon adj nitride)) and insulation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:15
S11 4	35	(undoped adj insulating) and (sin or (silicon adj nitride)) and insulating	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/17 15:15